

RJH60A85RDPE

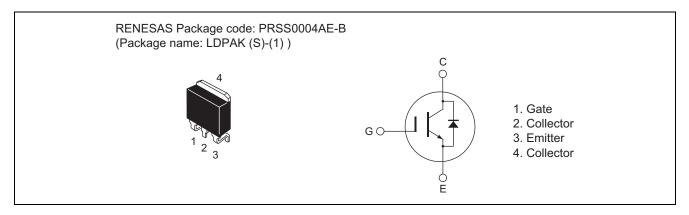
600V - 15A - IGBT Application: Inverter

R07DS0809EJ0200 Rev.2.00 Jul 12, 2012

Features

- Reverse conducting IGBT with monolithic diode
- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage
- $V_{CE(sat)} = 1.5 \text{ V typ.}$ (at $I_C = 15 \text{ A}$, $V_{GE} = 15 \text{ V}$, $Ta = 25^{\circ}\text{C}$)
- Built-in fast recovery diode ($t_{rr} = 160$ ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching $t_f = 110$ ns typ. (at V_{CC} = 300 V, V_{GE} = 15 V, I_C = 15 A, Rg = 5 Ω , Ta = 25°C, inductive load)

Outline



Absolute Maximum Ratings

				$(Ta = 25^{\circ}C)$
Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	600	V
Gate to emitter voltage		V _{GES}	±30	V
Collector current	Tc = 25°C	Ι _C	30	A
	Tc = 100°C	Ι _C	15	A
Collector peak current		I _{C(peak)} Note1	60	A
Collector to emitter diode forward current		İ _{DF}	15	A
Collector to emitter diode forward peak current		i _{DF(peak)} Note1	60	A
Collector dissipation		Pc ^{Note2}	113	W
Junction to case thermal resistance		θj-c ^{Note2}	1.11	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. $PW \le 10 \ \mu s$, duty cycle $\le 1\%$

2. Value at Tc = $25^{\circ}C$



Electrical Characteristics

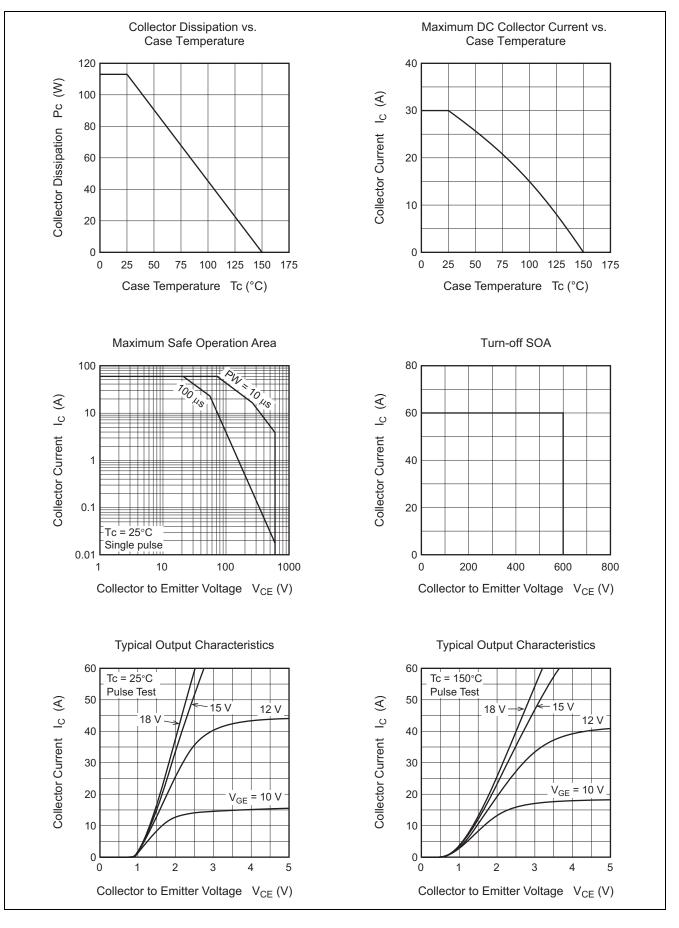
						$(Ta = 25^{\circ}C)$	
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Collector to emitter breakdown voltage	V _{(BR)CES}	600	—	—	V	$I_{C} = 10 \ \mu A, \ V_{GE} = 0$	
Zero gate voltage collector current / diode reverse current	I _{CES} / I _R	_	—	1	μA	$V_{CE} = 600 \text{ V}, \text{ V}_{GE} = 0 \text{ V}$	
Gate to emitter leak current	I _{GES}	_	—	±100	nA	$V_{GE} = \pm 30 \text{ V}, \text{ V}_{CE} = 0 \text{ V}$	
Gate to emitter cutoff voltage	V _{GE(off)}	4.5	—	7.5	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	V _{CE(sat)}	—	1.5	1.8	V	I_{C} = 15 A, V_{GE} = 15 V ^{Note3}	
	V _{CE(sat)}	—	1.9	—	V	$I_{C} = 30 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies	—	880	—	pF	V _{CE} = 25 V	
Output capacitance	Coes	—	48	—	pF	$V_{GE} = 0 V$	
Reveres transfer capacitance	Cres	_	35	—	pF	f = 1 MHz	
Total gate charge	Qg	_	56	—	nC	V _{GE} = 15 V	
Gate to emitter charge	Qge	_	8.4	—	nC	V _{CE} = 300 V	
Gate to collector charge	Qgc	_	33	—	nC	I _C = 15 A	
Turn-on delay time	t _{d(on)}	_	40	—	ns	$V_{CC} = 300 V$	
Rise time	tr	—	17	—	ns	V _{GE} = 15 V	
Turn-off delay time	t _{d(off)}	_	86	—	ns	I _C = 15 A	
Fall time	t _f	_	110	—	ns	$Rg = 5 \Omega$	
Turn-on energy	Eon	—	0.43	_	mJ	Inductive load	
Turn-off energy	E _{off}	—	0.30	—	mJ]	
Total switching energy	E _{total}	—	0.73	—	mJ]	
Short circuit withstand time	t _{sc}	3.0	5.0		μS	$\begin{array}{l} V_{CE} \leq 360 \ V, \ V_{GE} = 15 \ V \\ Tj {=} 100^{\circ}C \end{array}$	

FRD forward voltage	VF	—	1.7	—	V	I _F = 15 A ^{Note3}
FRD reverse recovery time	trr	—	160	—	ns	I _F = 15 A
FRD reverse recovery charge	Qrr	—	0.47	—	μC	di _F /dt = 100 A/µs
FRD peak reverse recovery current	١'n	—	7.5	—	А	

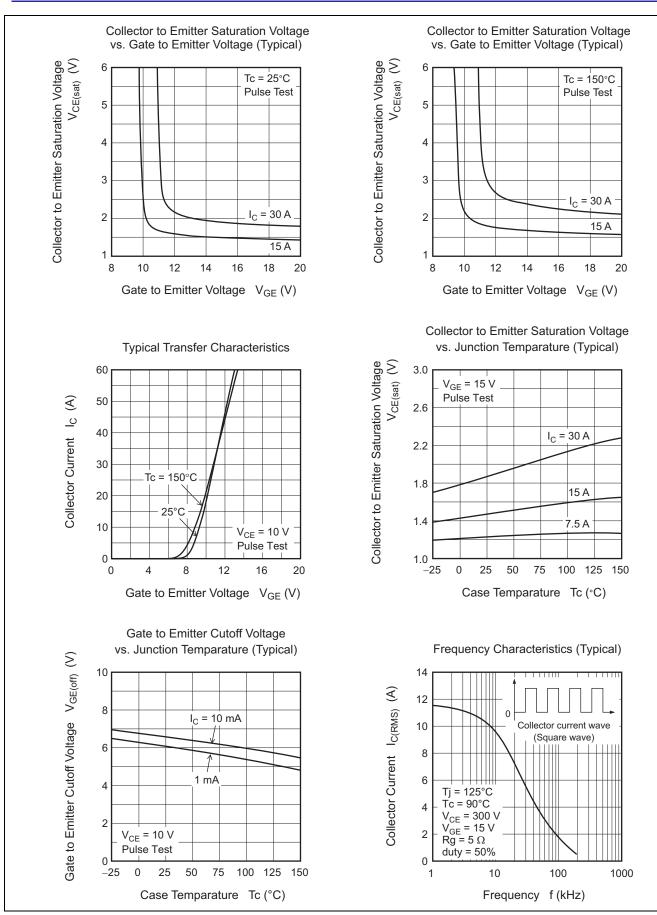
Notes: 3. Pulse test.

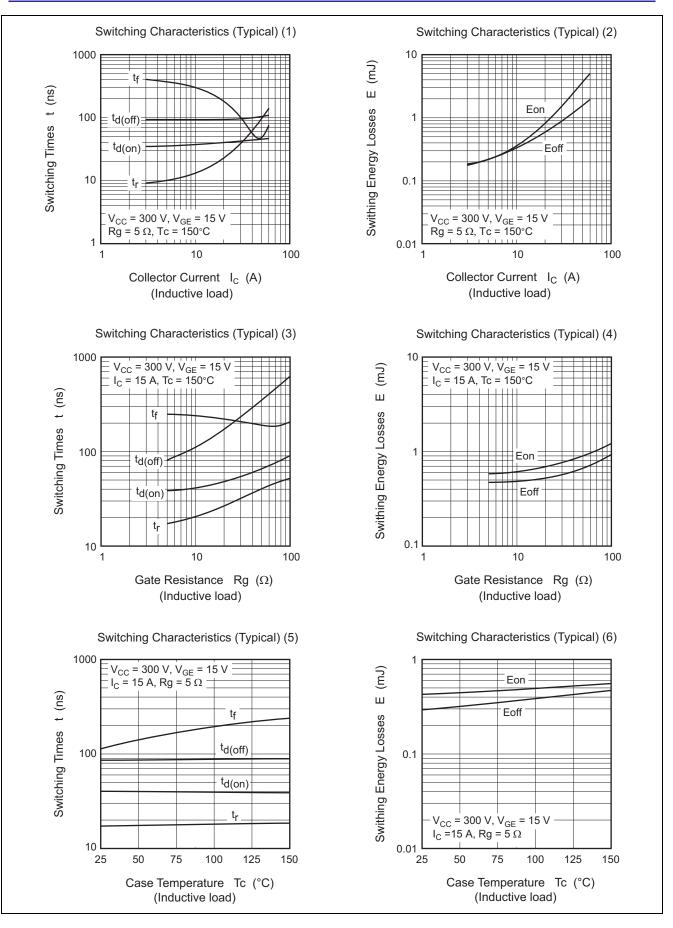


Main Characteristics

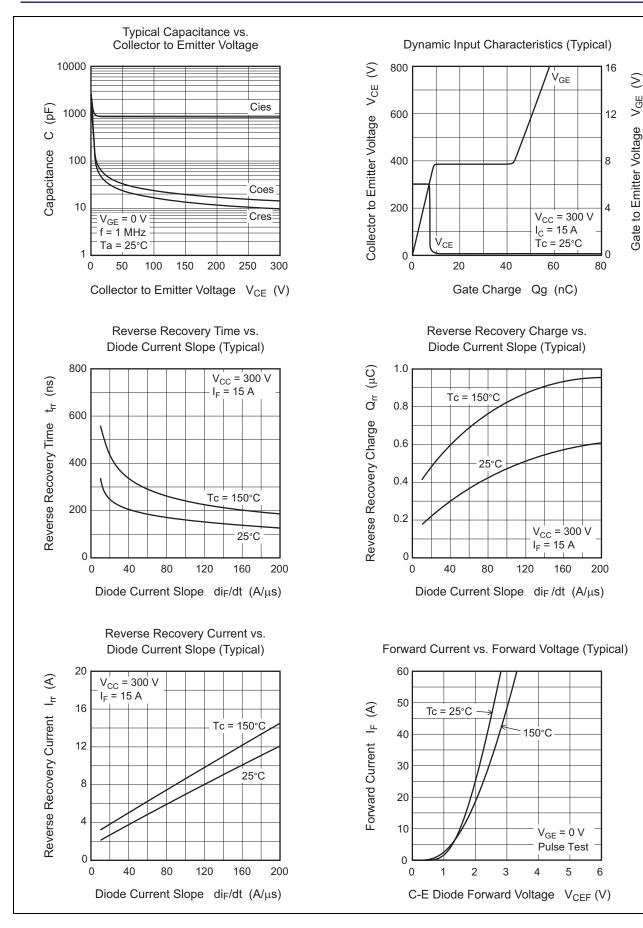




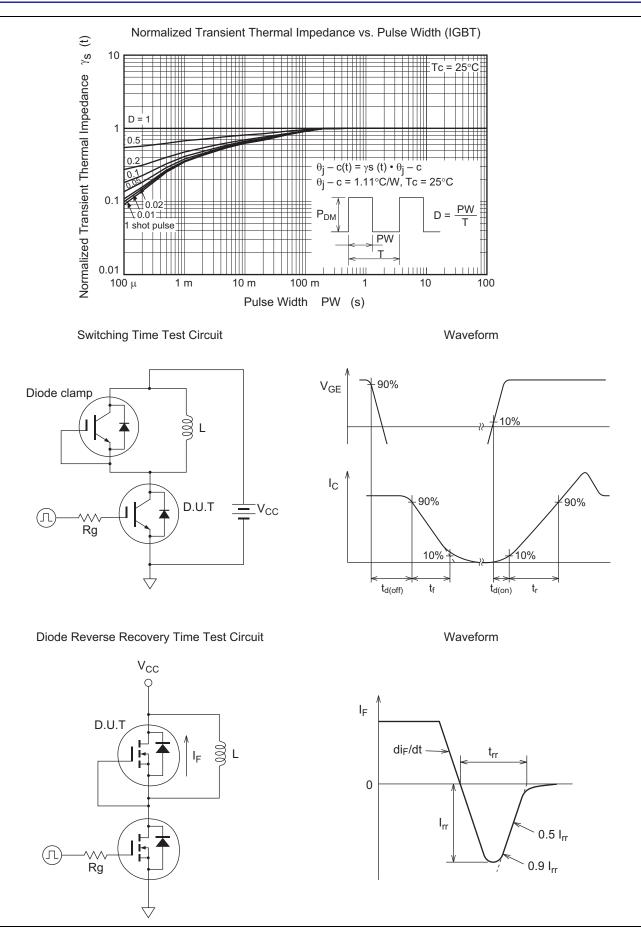






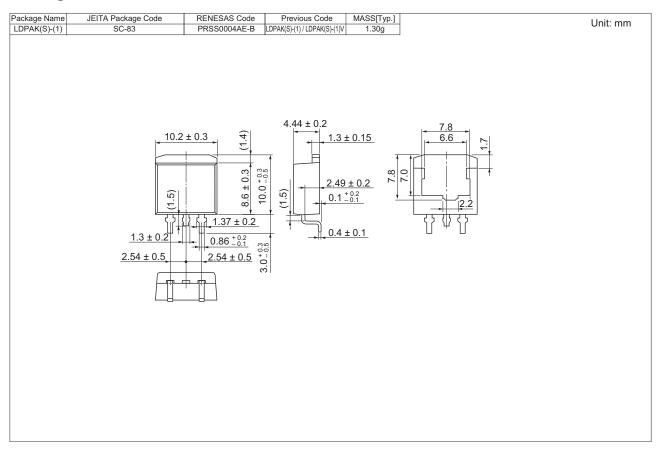








Package Dimension



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH60A85RDPE-00#J3	1000 pcs	Taping



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